FORM PTO-1449 (SUBSTITUTE)  U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE  INFORMATION DISCLOSURE				Attorney Docket No.: P2001,0373 Appl. No.:  Applicant: JUDITH MAGET				
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A		Burghartz, J. N. et al.: "Integrated RF and Microwave Components in BiCMOS Technology", IEEE Transactions on Electron Devices, Vol. 43, No. 9, September 1996, pp. 1559-1570						
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